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PATENT NUMBER and
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM 10091193	FILING DATE 03/05/2002	CLASS 257	SUBCLASS	GAU 2606 2811	EXAMINER Tian, Tan
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**APPLICANTS: Chen Howard, Hsu Louis, Wang Li-Kong;

**CONTINUING DATA VERIFIED.

THIS APPLICATION IS A CIP OF 09/579,044 05/26/2000

yes / / T

* FOREIGN APPLICATIONS VERIFIED: no / / T

PG-PUB DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO
Foreign priority claimed 35 USC 119 conditions met	<input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> yes <input checked="" type="checkbox"/> no	YOR91999-0420-US2
Verified and Acknowledged Examiner's initials	TJ	SERIAL OF COMM-PAT 5 1M PTO 475 (REV. 12-94)
TITLE : Semiconductor high dielectric constant decoupling capacitor structures and process for fabrication		

NOTICE OF ALLOWANCE MAILED		Assistant Examiner	CLAIMS ALLOWED	
			Total Claims	Print Claim for O.G
ISSUE FEE		DRAWING		
Amount Due	Date Paid	Sheets Drawg.	Fig. Drawg.	Print Fig.
<input type="checkbox"/> TERMINAL DISCLAIMER		Primary Examiner		
		PREPARED FOR ISSUE		
		Application Examiner		
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